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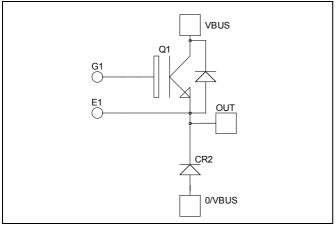


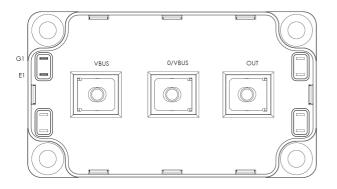


# APTGT400SK120G

 $I_{\rm C} = 400 {\rm A}$  @ Tc = 80°C

### Buck chopper Fast Trench + Field Stop IGBT3 Power Module





### Application

- AC and DC motor control
- Switched Mode Power Supplies

 $V_{CES} = 1200V$ 

### Features

- Fast Trench + Field Stop IGBT3 Technology
  - Low voltage drop
  - Low tail current
  - Switching frequency up to 20 kHz
  - Soft recovery parallel diodes
  - Low diode VF
  - Low leakage current
  - RBSOA and SCSOA rated
- Kelvin emitter for easy drive
- Very low stray inductance
  - Symmetrical design
  - M5 power connectors
- High level of integration

### Benefits

- Stable temperature behavior
- Very rugged
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- Easy paralleling due to positive TC of VCEsat
- Low profile
- RoHS Compliant

### Absolute maximum ratings

Symbol	Parameter		Max ratings	Unit	
V <sub>CES</sub>	Collector - Emitter Breakdown Voltage		1200	V	
т	Continuous Collector Current	$T_C = 25^{\circ}C$	560 *		
I <sub>C</sub>	Continuous Conector Current	$T_C = 80^{\circ}C$	400	А	
I <sub>CM</sub>	Pulsed Collector Current	$T_C = 25^{\circ}C$	800		
V <sub>GE</sub>	Gate – Emitter Voltage		±20	V	
PD	Maximum Power Dissipation	$T_C = 25^{\circ}C$	1785	W	
RBSOA	Reverse Bias Safe Operating Area	$T_j = 125^{\circ}C$	800A @ 1100V		

\* Specification of IGBT device but output current must be limited to 500A to not exceed a delta of temperature greater than 100°C for the connectors.

CAUTION: These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed. See application note APT0502 on www.microsemi.com



### All ratings (a) $T_j = 25^{\circ}C$ unless otherwise specified

### **Electrical Characteristics**

Symbol	Characteristic	Test Conditions		Min	Тур	Max	Unit
I <sub>CES</sub>	Zero Gate Voltage Collector Current	$V_{GE} = 0V, V_{CE} = 1200V$				750	μΑ
V <sub>CE(sat)</sub>	Collector Emitter Saturation Voltage	$ \begin{array}{c} V_{GE} = 15V & T_{j} = 25^{\circ}C \\ I_{C} = 400A & T_{j} = 125^{\circ}C \end{array} $	$T_j = 25^{\circ}C$	1.4	1.7	2.1	V
			$T_{j} = 125^{\circ}C$		2.0		v
V <sub>GE(th)</sub>	Gate Threshold Voltage	$V_{GE} = V_{CE}$ , $I_C = 4 \text{ mA}$		5.0	5.8	6.5	V
I <sub>GES</sub>	Gate – Emitter Leakage Current	$V_{GE} = 20V, V_{CE} = 0V$				800	nA

### **Dynamic Characteristics**

Symbol	Characteristic	Test Conditions		Min	Тур	Max	Unit
Cies	Input Capacitance	$V_{GE} = 0V$ $V_{CE} = 25V$ $f = 1MHz$			28		
Coes	Output Capacitance				1.6		nF
C <sub>res</sub>	Reverse Transfer Capacitance				1.2		
T <sub>d(on)</sub>	Turn-on Delay Time	Inductive Switching (2	25°C)		260		
Tr	Rise Time	$V_{GE} = \pm 15V$			30		
T <sub>d(off)</sub>	Turn-off Delay Time	$V_{Bus} = 600V$ $I_C = 400A$ $R_G = 1.2\Omega$			420		ns
$T_{\rm f}$	Fall Time				80		
T <sub>d(on)</sub>	Turn-on Delay Time	Inductive Switching (	125°C)		290		
Tr	Rise Time	$V_{GE} = \pm 15V$ $V_{Bus} = 600V$ $I_{C} = 400A$ $R_{G} = 1.2\Omega$			50		ns
T <sub>d(off)</sub>	Turn-off Delay Time				520		
$T_{\rm f}$	Fall Time				100		
Eon	Turn on Energy	$\begin{array}{c} V_{GE} = \pm 15V \\ V_{Bus} = 600V \end{array} \qquad T_j =$	125°C		40		mJ
$E_{\text{off}}$	Turn off Energy	$\begin{array}{c} I_C = 400A \\ R_G = 1.2\Omega \end{array} \qquad T_j = \end{array}$	125°C		40		111J

### Chopper diode ratings and characteristics

Symbol	Characteristic	Test Conditions		Min	Тур	Max	Unit
V <sub>RRM</sub>	Maximum Peak Repetitive Reverse Voltage			1200			V
I <sub>RM</sub>	Maximum Reverse Leakage Current	V <sub>R</sub> =1200V	$T_i = 25^{\circ}C$ $T_i = 125^{\circ}C$			700 900	μΑ
I <sub>F</sub>	DC Forward Current		$Tc = 80^{\circ}C$		400		А
$V_{\rm F}$	Diode Forward Voltage	$I_{\rm F} = 400 A$ $V_{\rm GE} = 0 V$	$T_i = 25^{\circ}C$		1.6	2.1	V
v F			$T_{i} = 125^{\circ}C$		1.6		v
t <sub>rr</sub>	Reverse Recovery Time	L - 100 A	$T_j = 25^{\circ}C$		170		ns
۹rr			$T_{j} = 125^{\circ}C$		280		
0	Reverse Recovery Charge	$I_F = 400A$ $V_R = 600V$ $di/dt = 4000A/\mu s$	$T_j = 25^{\circ}C$		36		uС
Q <sub>rr</sub>	Reverse Recovery Charge		$T_{j} = 125^{\circ}C$		72		μC
Er	Reverse Recovery Energy	J	$T_j = 25^{\circ}C$		20		mI
			$T_{j} = 125^{\circ}C$		36		mJ

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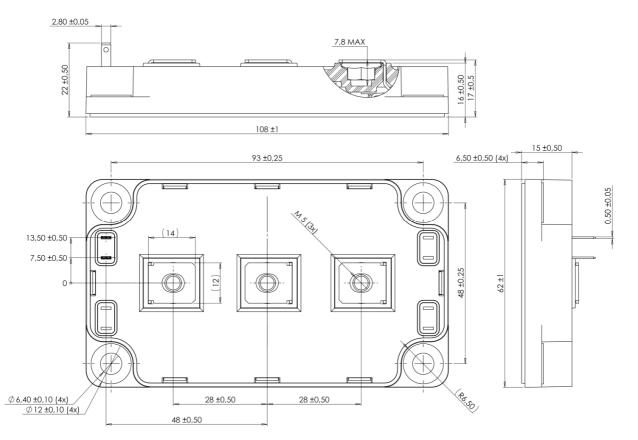
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### Thermal and package characteristics

Symbol	Characteristic			Min	Тур	Max	Unit
R <sub>thJC</sub>	Junction to Case Thermal Resistance		IGBT			0.07	°C/W
<b>R</b> <sub>th</sub> JC			Diode			0.13	C/ W
V <sub>ISOL</sub>	RMS Isolation Voltage, any terminal to case t =1 min, 50/60Hz			4000			V
T <sub>J</sub>	Operating junction temperature range			-40		150	
T <sub>STG</sub>	Storage Temperature Range					125	°C
T <sub>C</sub>	Operating Case Temperature					100	
Torque	Mounting forage	To heatsink	M6	3		5	N.m
Torque		For terminals	M5	2		3.5	19.111
Wt	Package Weight					300	g

### SP6 Package outline (dimensions in mm)

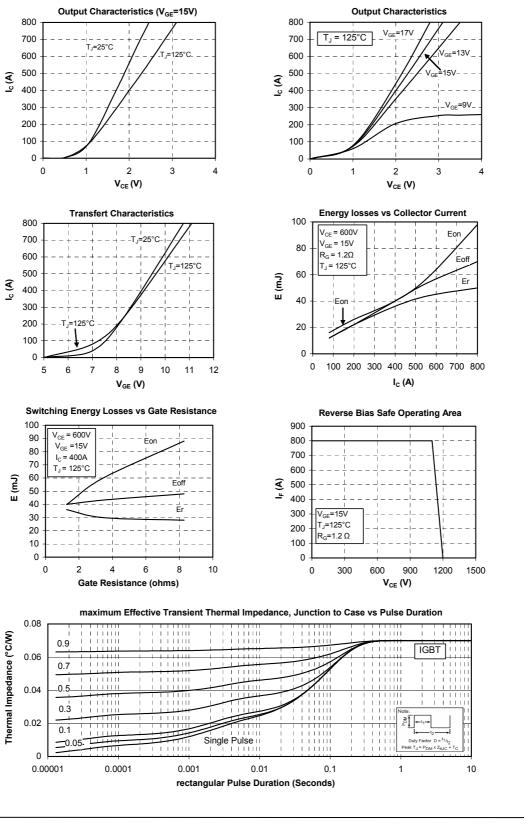


See application note APT0601 - Mounting Instructions for SP6 Power Modules on www.microsemi.com

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### **Typical Performance Curve**

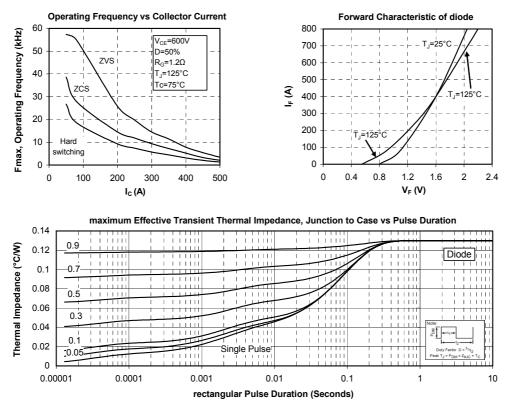


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